NSN 5961-01-113-8320

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-113-8320 **Inclosure Material:** Glass **Overall Length:** 3.000 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Terminal Type And Quantity:** 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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